

High Efficiency, synchronous PFM step-up DC-DC converter

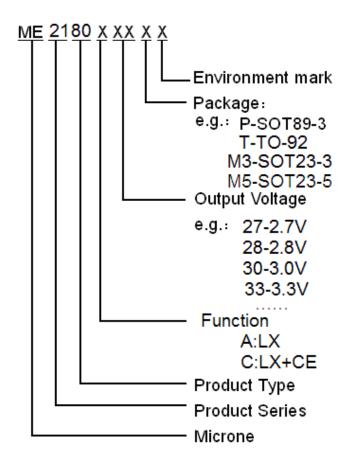
General Description

ME2180 Series is a PFM Step-up DC/DC converter IC with low supply current by CMOS process. High frequency noise that occurs during switching is reduced by using advanced circuit designed, output voltage is programmable in 0.1V steps between 2.5~5.0V and maximum frequency is 250KHz(TYP.). A low ripple, high efficiency step-up DC/DC converter can be constructed of ME2180Xxx with only two external components. ME2180Xxx is suitable for use with battery-powered instruments with low noise and low supply current.

Features

- High efficiency: 95%
- Maximum frequency: 250KHz
- Low Quiescent Current: 15uA
- Input Voltage: 0.9V~5.0V
- Output Voltage Range:2.5V to 5.0V
- High Accuracy: ± 2%
- Low ripple and Low noise
- Package:SOT89-3, SOT23-3, TO-92, SOT23-5

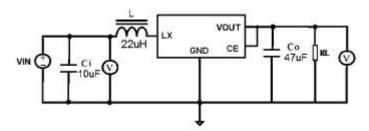
Selection Guide



Typical Application

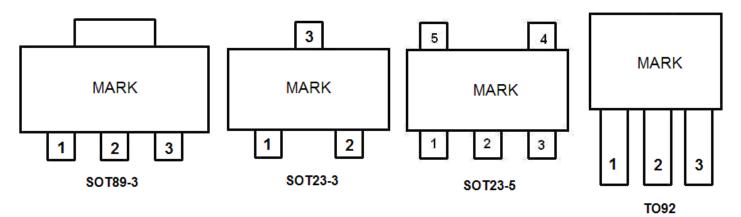
- Power source for battery-powered equipment
- Power source for Wireless mouse,toys,
 Cameras, VCRs, PDAs, MP3, and Led lighting etc

Typical Application Circuit





Pin Configuration



Pin Assignment

TYPE	POSTFIX	PACKAGE	SWITCHING	OF FUNCTION	FEATURES	
			TRANSISTOR	CE FUNCTION		
ME2180Axx	МЗ	SOT23-3	Build in Transistor			
	Р	SOT89-3		No	Lx	
	Т	TO92				
ME2180Cxx	M5	SOT23-5	Build in Transistor	Yes	LX+CE	

ME2180AXX

Pin Number			Pin Name	Description
SOT89-3	SOT23-3	TO-92		
1	1	1	GND	Ground
2	3	2	VOUT	Voltage output
3	2	3	LX	Switch pin

ME2180AXX-DS

Pin Number	Pin Name	Description
SOT23-3		
1	GND	Ground
2	VOUT	Voltage output
3	LX	Switch pin

ME2180CXX

PIN Number	Pin Name	Function
SOT23-5	Pin Name	Function
1	CE	Chip enable
2	VOUT	Output voltage monitor, IC internal power supply
3	NC	NC
4	GND	Ground
5	LX	Switch

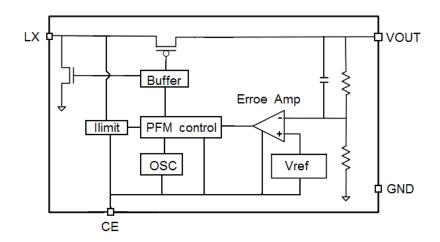
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Absolute Maximum Ratings

Parameter	Symbol	Ratings	Units	
Supply Voltage	V_{max}	8	V	
LX pin current	ILXmax	1000	mA	
	SOT23	P _D	300	mW
Continuous Total Power Dissipation	SOT89	P _D	500	mW
	TO92	P _D	500	mW
Operating Temperature Rai	T _{OPR}	−20 ~+85	${\mathbb C}$	
Storage Temperature Ran	T _{STG}	−40~125	${\mathbb C}$	
ESD	Vesd	2000	V	

Block Diagram



Electrical Characteristics

 $T_{A}\!\!=\!\!25^{0}\!C,\,V_{in}\!\!=\!\!Vout\times0.6V,\,L\!\!=\!\!22uH,\;\;Cin\!\!=\!\!10u,\;\;Cout\!\!=\!\!47u,\,unless\;otherwise\;noted.$

ME2180Axx/Cxx

Symbol	Parameter	Test Conditions	MIN	TYP	MAX	UNIT
V _{OUT}	Output Voltage		Vout×0.98	Vout	Vout×1.02	V
V _{in}	Supply Voltage		0.9		5	V
Vstart	Start voltage	Iload=1mA, Vin: 0→2V			0.95	V
Vhold	Hold voltage	Iload=1mA, Vin: 2→0V	0.5			V
Fosc	oscillation frequency			250		KHz
η	Efficiency			90	95	%
llimit	Current limit		800	1000	1200	mA
lin	Quiescent Current			15		uA

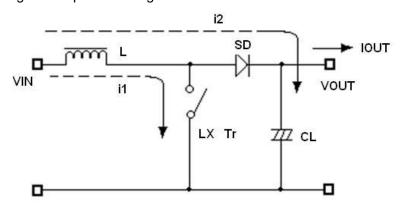
Note: 1 \ Inductor: $22\mu H (r<0.5\Omega)$ 2 \ Capacitor: Tantalum type

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Operation Description

ME2180 step-up DC/DC converter charges energy in the inductor when Lx Transistor is on, and discharges the energy with the addition of the energy from input power source thereto, so that a higher output voltage than the input voltage is obtained. Following is the operation diagram.



Switching DC/DC Step up Converter operating process

PCB Layout:

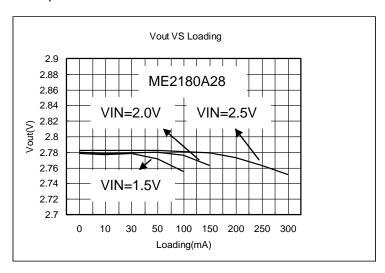
- Set external components as close as possible to the IC and minimize the connection between the components and the IC. In particular, when an external component is connected to VOUT Pin, make minimum connection with the capacitor.
- ♦ Make Vss pin sufficient grounding, otherwise, the zero level within IC will varied with the switching current. This may result in unstable operation of IC.

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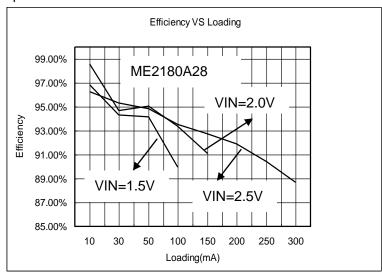


Type Characteristics

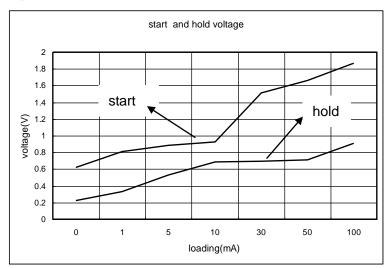
1、 output voltage VS output current



2、efficiency VS output current



3. Start & Hold voltage VS output current

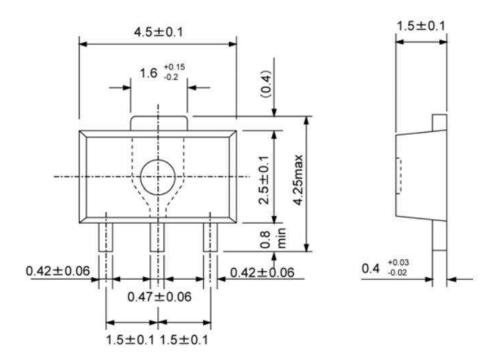


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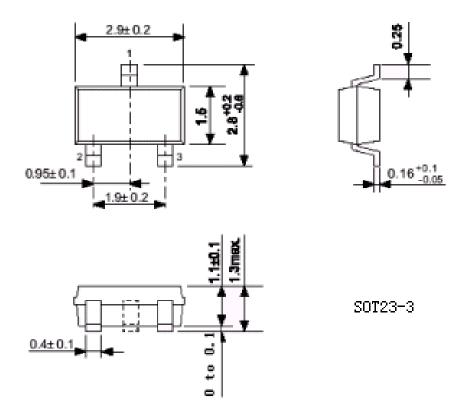


Packaging Information

● SOT89-3



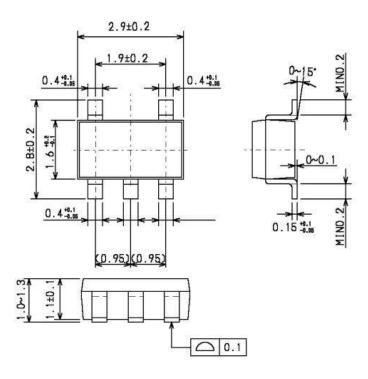
● SOT23-3



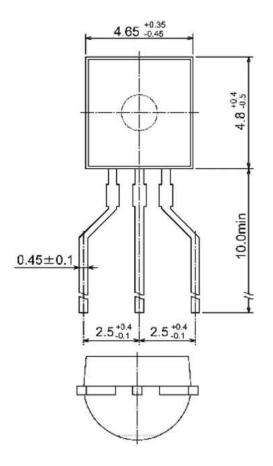
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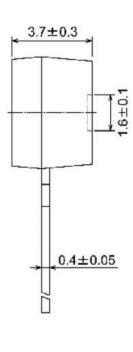


●SOT23-5



● TO-92







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